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# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









. :eescale Semiconductor
Technical Data

Gallium Arsenide CATV Amplifier Module

### **Features**

- 79-, 112- and 132-Channel Loading
- Excellent Distortion Performance
- Integrated ESD Protection Diodes
- GaAs FET Transistor Technology
- Unconditionally Stable Under All Load Conditions

#### **Applications**

- CATV Systems Operating in the 40 to 1000 MHz Frequency Range
- Input Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Driver Amplifier in Linear General Purpose Applications

#### Description

- 24 Vdc Supply, 40 to 1000 MHz, CATV GaAs Forward Amplifier Module
- RoHS Compliant

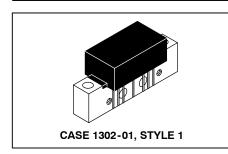
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Rev. 0, 7/2006

**√RoHS** 

# MHW10276N

1000 MHz 27.8 dB GAIN 132-CHANNEL GaAs CATV AMPLIFIER MODULE



# **Table 1. Maximum Ratings**

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V <sub>in</sub>	+65	dBmV
DC Supply Voltage	V <sub>CC</sub>	+26	Vdc
Operating Case Temperature Range	T <sub>C</sub>	T <sub>C</sub> -20 to +100	
Storage Temperature Range	T <sub>stg</sub>	-40 to +100	°C

### **Table 2. ESD Maximum Ratings**

Rating	Input Value	Output Value	Unit
Surge Voltage per IEC 1000-4-5	200	200	V
Human Body Model per Mil. Std. 1686	2	2	kV

## **Table 3. Electrical Characteristics** ( $V_{CC}$ = 24 Vdc, $T_{C}$ = +30°C, 75 $\Omega$ system unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
Frequency Range		BW	40	_	1000	MHz
Power Gain	1000 MHz	Gp	27	27.8	28.5	dB
Slope	50-1000 MHz	S	0.3	0.9	1.45	dB
Gain Flatness (40-995 MHz, Peak-to-Val	ley)	G <sub>F</sub>	_	_	0.8	dB



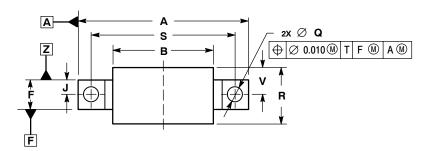
**Table 3. Electrical Characteristics** ( $V_{CC}$  = 24 Vdc,  $T_{C}$  = +30°C, 75  $\Omega$  system unless otherwise noted) (continued)

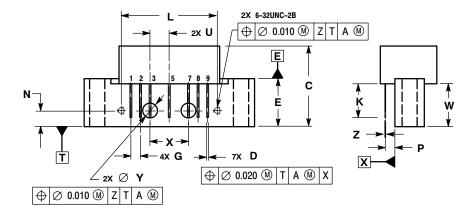
Characteristic		Symbol	Min	Тур	Max	<b>Unit</b> dB
Input Return Loss (Z <sub>0</sub> = 75 Ohms)	IRL					
, , ,	40-200 MHz		20	_	_	
	201-600 MHz		19	_	_	
	601 -870 MHz		18	_		
	871-1000 MHz		14.5	_	_	
Output Return Loss (Z <sub>o</sub> = 75 Ohms)		ORL				dB
	40-200 MHz		20	_	_	
	201 - 600 MHz		18			
	601 -870 MHz		18	_		
	871-1000 MHz		12.5	_	_	
Composite Second Order						dBc
(Vout = +44 dBmV/ch., Worst Case)	79-Channel FLAT	CSO <sub>79</sub>	_	-70	-64	
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	112-Channel FLAT	CSO <sub>112</sub>		-66	-62	
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	132-Channel FLAT	CSO <sub>132</sub>	_	-66	-60	
Cross Modulation Distortion @ Ch 2						dBc
$(V_{out} = +44 \text{ dBmV/ch.}, FM = 55.25 \text{ MHz})$	79-Channel FLAT	XMD <sub>79</sub>		-60	-53	
$(V_{out} = +44 \text{ dBmV/ch.}, FM = 55.25 \text{ MHz})$	112-Channel FLAT	XMD <sub>112</sub>	_	-60	-53	
$(V_{out} = +44 \text{ dBmV/ch.}, FM = 55.25 \text{ MHz})$	132-Channel FLAT	XMD <sub>132</sub>	_	-60	-53	
Composite Triple Beat						dBc
$(V_{out} = +44 \text{ dBmV/ch.}, \text{Worst Case})$	79-Channel FLAT	CTB <sub>79</sub>		-71	-65	
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	112-Channel FLAT	CTB <sub>112</sub>	_	-68	-61	
$(V_{out} = +44 \text{ dBmV/ch., Worst Case})$	132-Channel FLAT	CTB <sub>132</sub>	_	-66	-60	
Noise Figure	50 MHz	NF	_	5	5.5	dB
	550 MHz		_	5		
	750 MHz		_	5		
	1000 MHz		_	5	6.5	
DC Current (V <sub>DC</sub> = 24 V, T <sub>C</sub> = 45°C)		I <sub>DC</sub>	235	250	265	mA



**ARCHIVE INFORMATION** 

### **PACKAGE DIMENSIONS**





- NOTES:
  1. DIMENSIONS ARE IN INCHES.
  2. INTERPRET DIMENSIONS AND INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α		1.775		45.085	
В		1.085		27.559	
С		0.840		21.336	
D	0.015	0.021	0.381	0.533	
E	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.62	8.255	
G	0.100 BSC		2.540 BSC		
J	0.156	BSC	3.962	BSC	
K	0.315	0.355	8.001	9.017	
L	1.000	BSC	25.400 BSC		
N	0.165	BSC	4.191 BSC		
P	0.100	BSC	2.540	BSC	
Q	0.148	0.168	3.759	4.267	
R		0.600		15.24	
S	1.500 BSC		38.100 BSC		
U	0.200	BSC	5.080	BSC	
V		0.250		6.350	
W	0.435		11.049		
X	0.400 BSC		10.160 BSC		
Y	0.152	0.163	3.861	4.140	
Z	0.009	0.011	0.229	0.279	

- STYLE 1:
  PIN 1. RF INPUT
  2. GROUND
  3. GROUND
  4. DELETED
  5. VDC
  6. DELETED
  7. GROUND
  8. GROUND
  9. RF OUTPUT

**CASE 1302-01 ISSUE E** 

# How to Reach Us:

Home Page:

www.freescale.com

E-mail:

support@freescale.com

#### **USA/Europe or Locations Not Listed:**

Freescale Semiconductor Technical Information Center, CH370 1300 N. Alma School Road Chandler, Arizona 85224 +1-800-521-6274 or +1-480-768-2130 support@freescale.com

Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH Technical Information Center Schatzbogen 7 81829 Muenchen, Germany +44 1296 380 456 (English) +46 8 52200080 (English) +49 89 92103 559 (German) +33 1 69 35 48 48 (French) support@freescale.com

#### Japan:

Freescale Semiconductor Japan Ltd. Headquarters ARCO Tower 15F 1-8-1, Shimo-Meguro, Meguro-ku, Tokyo 153-0064 Japan 0120 191014 or +81 3 5437 9125 support.japan@freescale.com

#### Asia/Pacific:

Freescale Semiconductor Hong Kong Ltd.
Technical Information Center
2 Dai King Street
Tai Po Industrial Estate
Tai Po, N.T., Hong Kong
+800 2666 8080
support.asia@freescale.com

#### For Literature Requests Only:

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